

(19)
(12)

(KR)
(A)

(51) 。 Int. Cl.7
G02F 1/1335

(11)
(43)

2003-0071114
2003 09 03

(21) 10-2002-0010657
(22) 2002 02 27

(71) . 20

(72) 1027-15

2 1027-3

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(74)

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(54)

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4 3 - ` ,

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6 2 ,

7 6 - ` ,

8 1 ,

9a 9d 8 - ` , 1 ,

10 1 ,

11 2 ,

12 2 ,

13a 13d 14a 14d 12 - ` XI-XI` , 2

< >

100 : 102 :

104 : 108 :

112 : 114 :

116 : 124 :

126 : 130 :

(liquid crystal display device) ,
 (Transflective liquid crystal display device) .

(backlight) ,
 (power consumption) .

1

(13) , (15) , (P) (11) , (16) (17)
 (T) (25,39)

(21)

(A) (49) (61) (B) (D)

(15) (21) (14)

가 , 2

2 1 -

(14) (15) (F2) (11) (49) (F2) (13) (Image)

(F1) (Transmission mode) (41) (61) (21) (61) (14) (14) (41)

(61) (13) (14) (14) (41)

(B) (D) (F1,F2) 가

(F1) (D) (F2) (14) 가 (B)

(D) (B) 가

3 4

3 1

pe) (21) (T) 가 (T)가 (25) (matrix ty (39)

(25) (39) (P)

(49) (P) (49,61) (61) (A)

(B) (B) (D) () ()

(B) (D)

()

4 1

4 3 -

3) (D) (B) (A) (49) (25) (6)
(22,23) (27) (B)

() d 2*d

(B) (D) (I) 가

(21) (63) (49)³ (B) (I) (G1)

5

5

(50)가 (G1) (B)

(contrast ratio)

6 7

6 7 6 - 2 (K)

6 7 (B) (D) (A) (49)
(25) (I) (61) 2

(B)

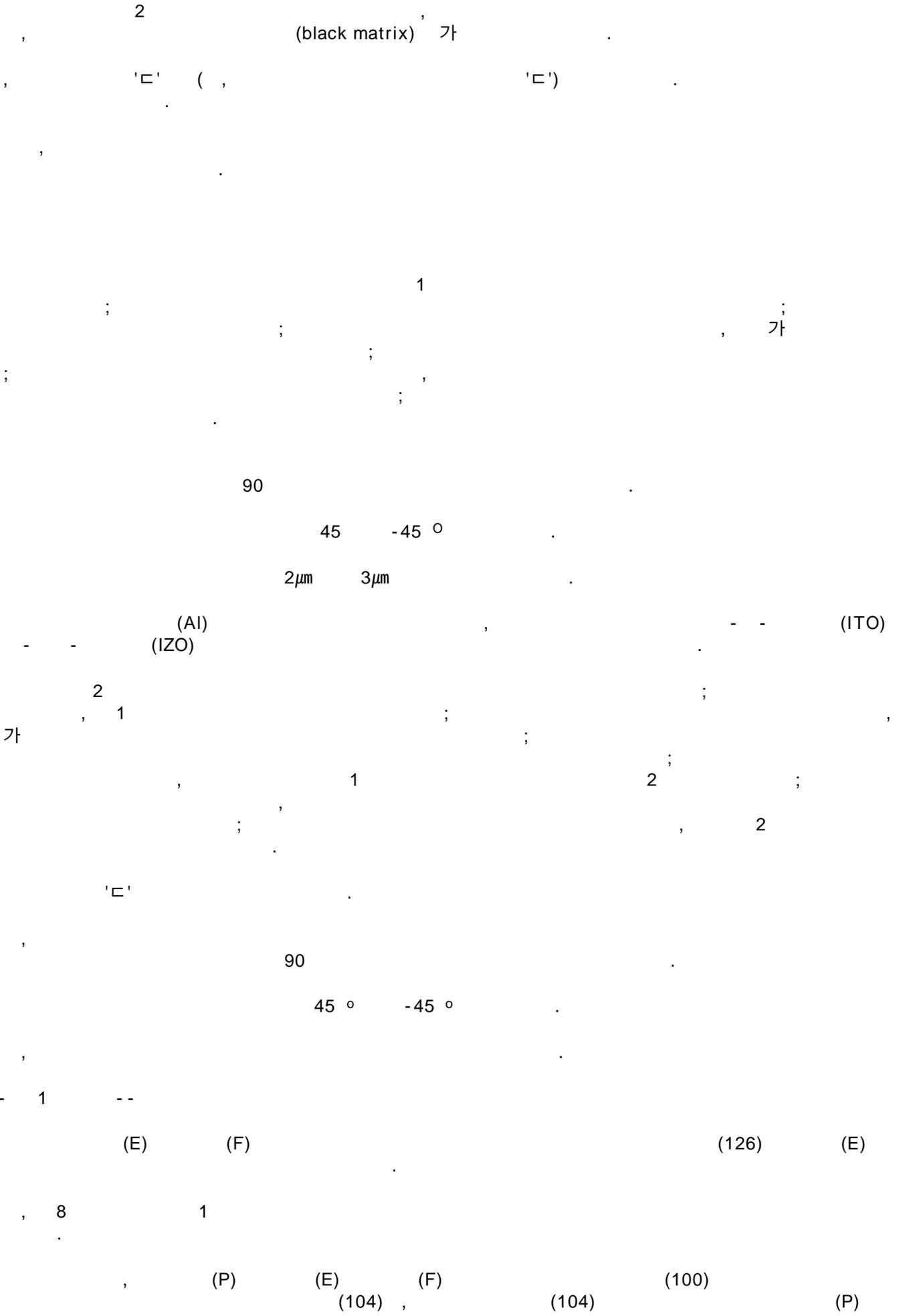
1

가 (7 I)
가

/ 가

2

1



(116)

(104) (116) (102) (108) (112)

(114) (T) (C) (C) (116) 1

(P) 1 (C) / (115) 2

(P) (E) (124) (126)

(114) (136) ()

(126) (124) (K) 2 μ m 3

(126) (floating) (114)

(rubbing) (G2)() 45^o (rubbing processing)

(126) (G2) (E) (U)

(E)가 (45^o)(G2)

(126)

(E) 가

가

(126) (E)

9a 9d 1

9a 9d 8 - 1

9a (P) (100) (104)

(104) (P) (102)

(Al) RC (delay) (hillock)

k) Al/Cr)가 (Al/Mo)

(104) (100) (SiN_x) (SiO_x)

(106)

(102) (106) (n+a-Si:H) (a-Si:H)

) (108)(active layer) (110)(ohmic contac

t layer)

9b (110) (Cr), (Mo), (Sb), (Ti)
 (104) (E) (F) (112) (P) (114), (116)

(104) / (115)

(104) 1 (115) 2
 (C)가

(112) (114) (112,114)
 (110) (108)

esin) (116) (100) (BCB) (acryl) (r
 (E) 1 (118) 2 (106) 1 (118) (122)

(106)

9c 1 (118) (Al)
 (126) (122) (124)

(126) (112,114) (114)
 (127)

(126) (P) (E) (F)

(126) (K) (8 G2)
 (E) (U)

(E) 'Γ' (126)

(126)₃ 2 (SiN_x) (SiO₂)
 (128)

2 1 2 (128) (126) (127) 2 (128)
 2 (118) (114) (132)
 (115) (134)

9d 2 (128) (100) - - (ITO)
 - - (IZO) 2 (115) (136)

-45 ° 45 °

1

10 11

10 11

10 (black) (white)
) ()가 (

11

(150a,150b)

(contrast ratio)가 가

(contrast)

2

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2

'ㄷ'

'ㄷ'

12

2

(P)

(E)

(F)
(204)

(204)

(200)

(P)

(216)

(214)
(204)

(216)
(T)

(202)

(208)

(212)

(P)

1

(205)

(C)

(214)

(C)

1

(205)

(204)

(P)

(215)

(P)

2

(E)

'ㄷ'

(214)
(224)

'ㄷ'
가

(226)

(230)

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(K)

(224)
(K1)

(216)

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(226)

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(230)

(216)

4μm

(226) 가

(216)

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(K)

(black matrix)(300)

(200)

(G3)

()
,

(rubbing processing)

(226)

(G3)

(E)

(U)

(E)가

(226)

(45 °)(G3)

┌

(E) 가

가

(E) 가

2

(226) (C)

(114)

1 (230)

13a 13d 14a 14d 2

13a 13d 14a 14d 12 - XI-XI` 2

13a 14a (P) (200)

(202) (204)

(204) 1 (205)

RC (delay)

(Al) (hilloc)

k) Al/Cr가 (Al/Mo)

(204) (200) (SiN_x) (SiO_x)

(206)

(202) (206) (n+a-Si:H) (a-Si:H)

) (208)(active layer) (210)(ohmic contac

t layer)

13b 14b (210) (Cr), (Mo), (Sb),

(Ti) (212) (216) (212)

(214) (213) 1 (205)

2 (115)

(206) 2 (215) 1 (205)

(C)

(212) (214) (212,214)

(210) (208)

(216) (200) (BCB) (acryl) (r

esin) 2 1 (218)

06) 1 (118) (P) 1 (218) (2

(222)

(222) (P) (K)

(226)

13c 14c 1 (218) (Al)

(224) (226) (222)

가

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(Al)

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(ITO)

- -

(IZO)

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-45 °

12.

8

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(Al)

13.

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- -

(ITO)

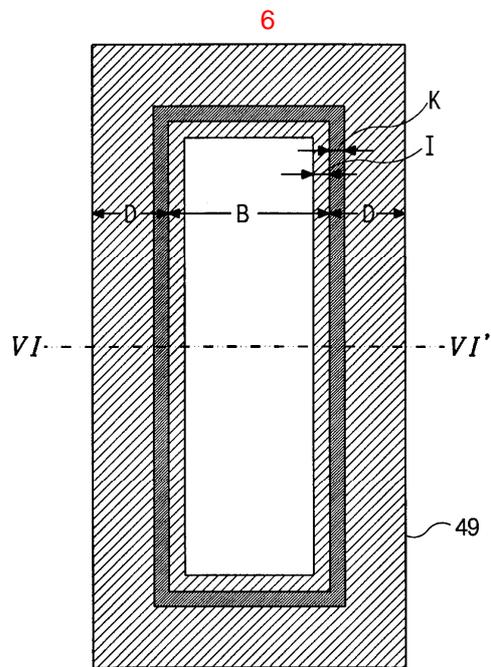
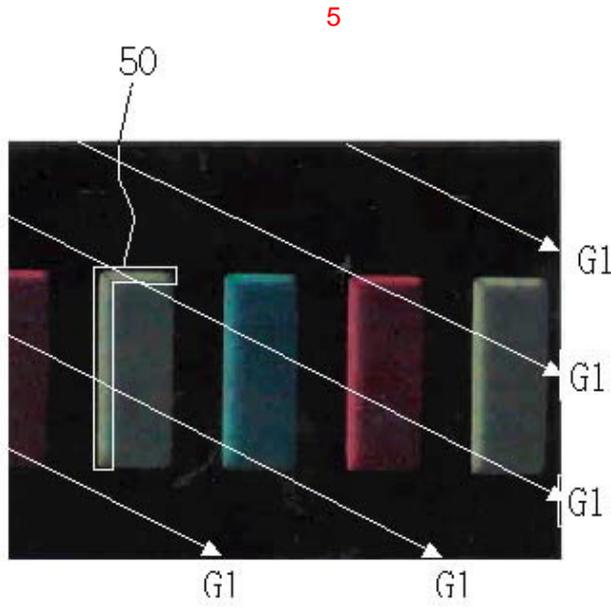
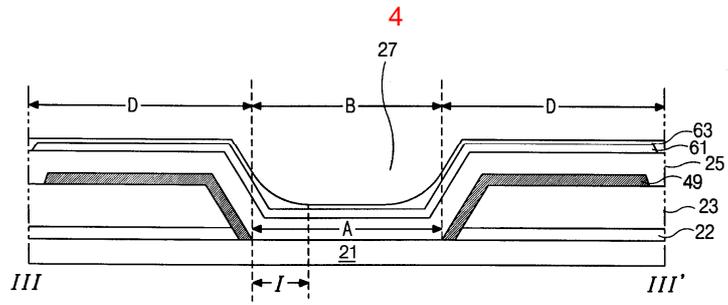
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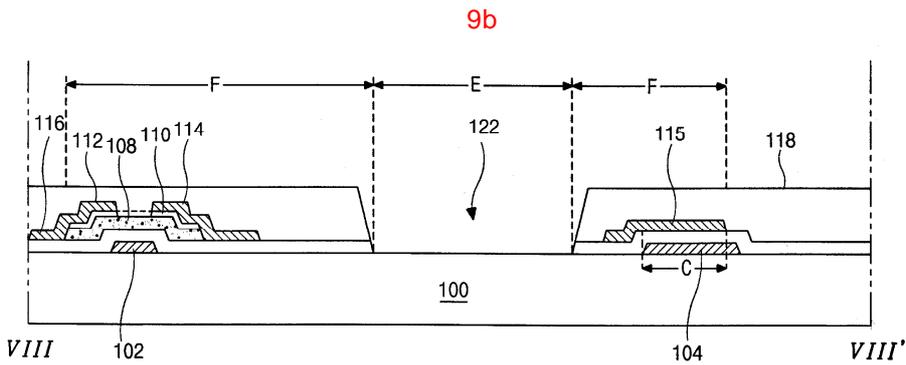
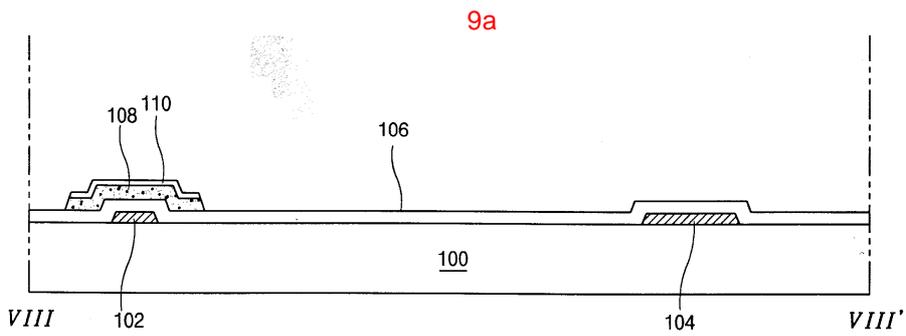
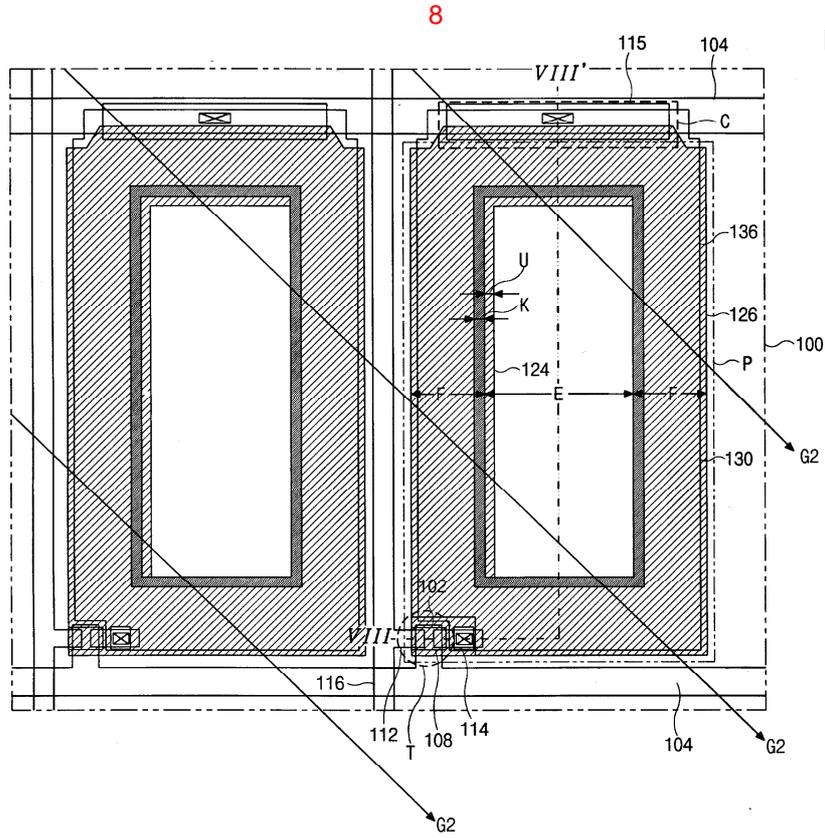
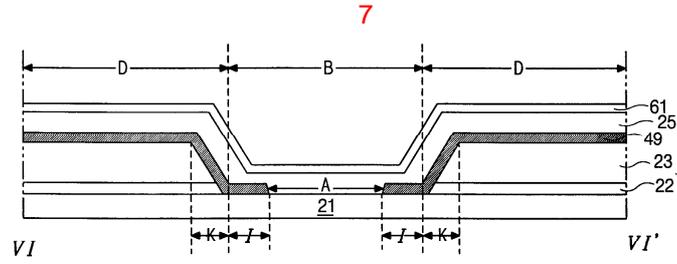
(IZO)

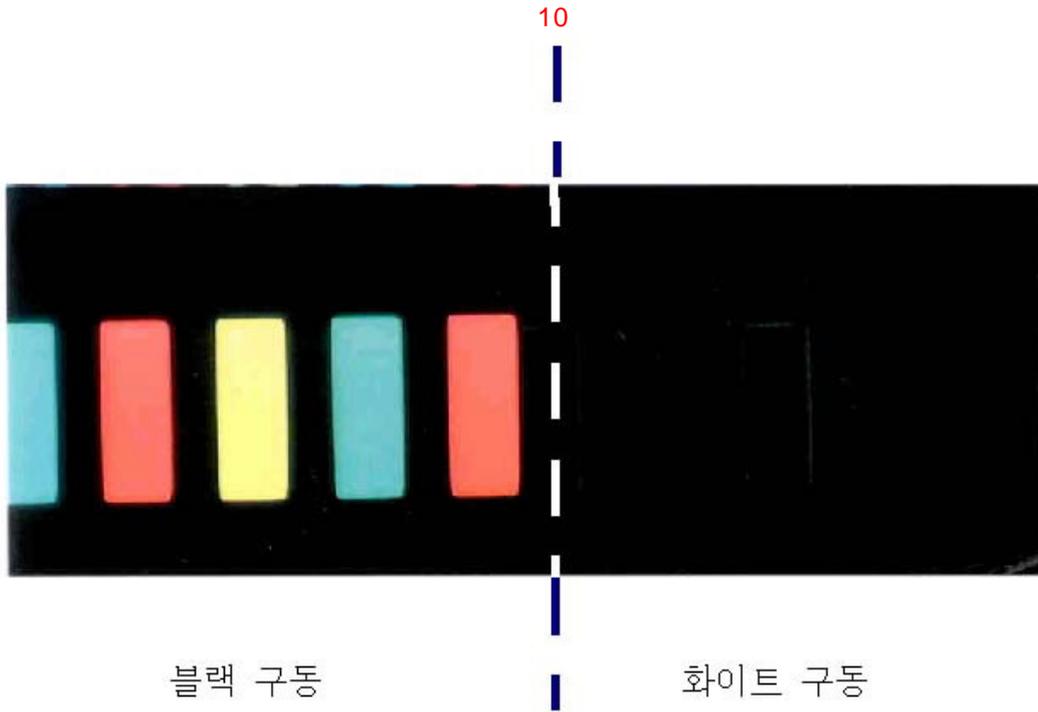
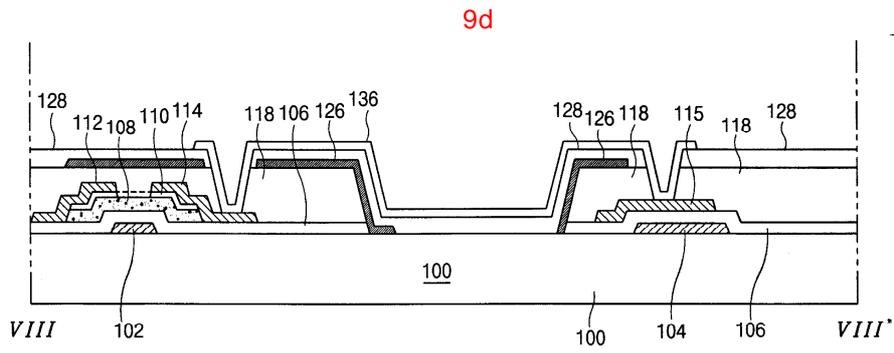
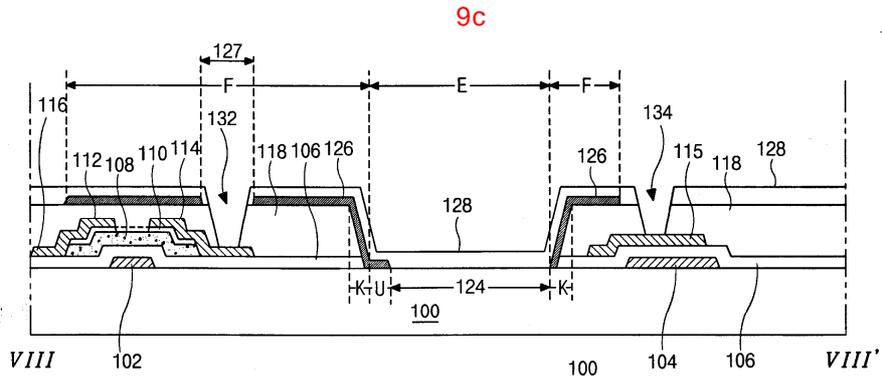
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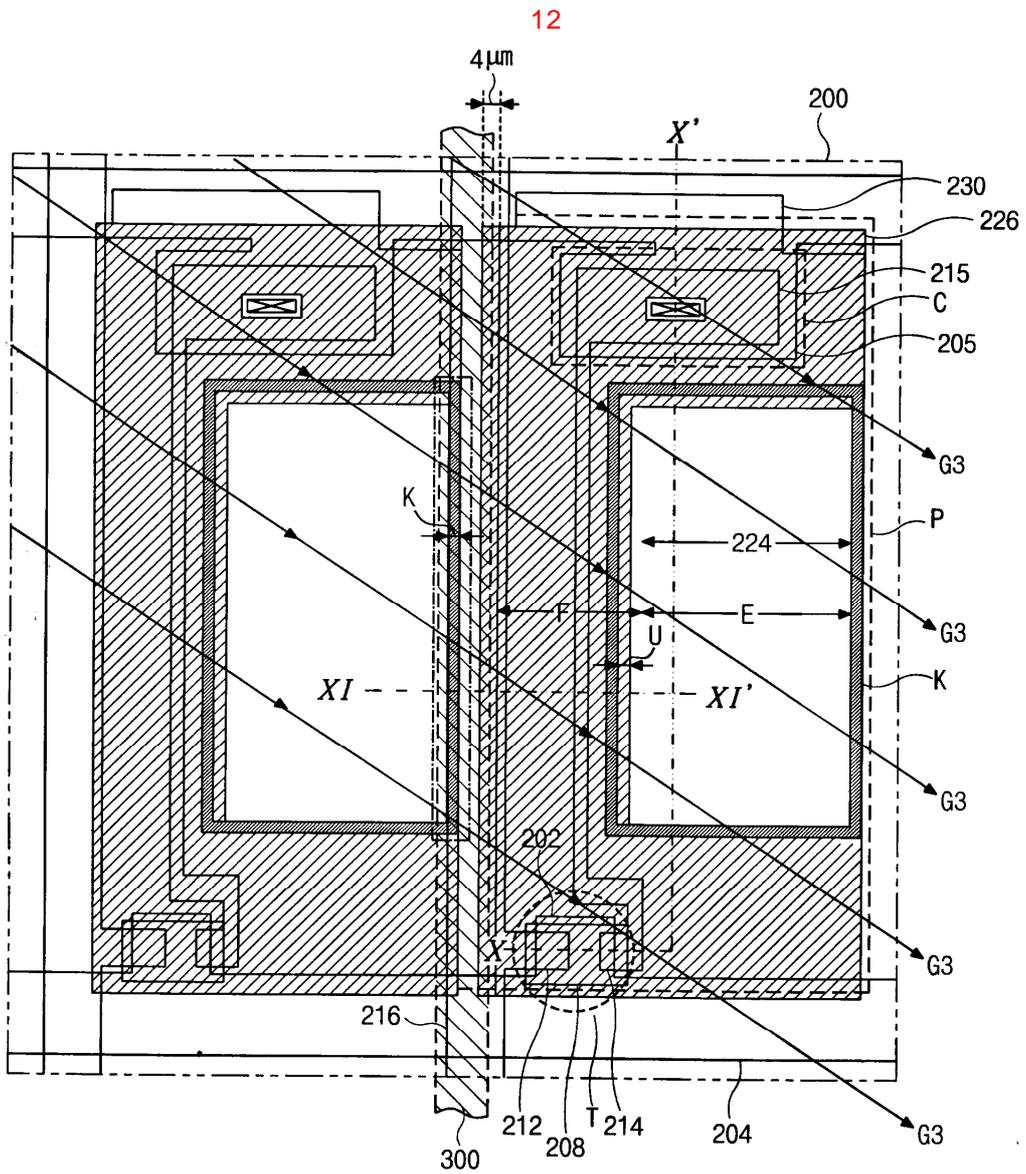
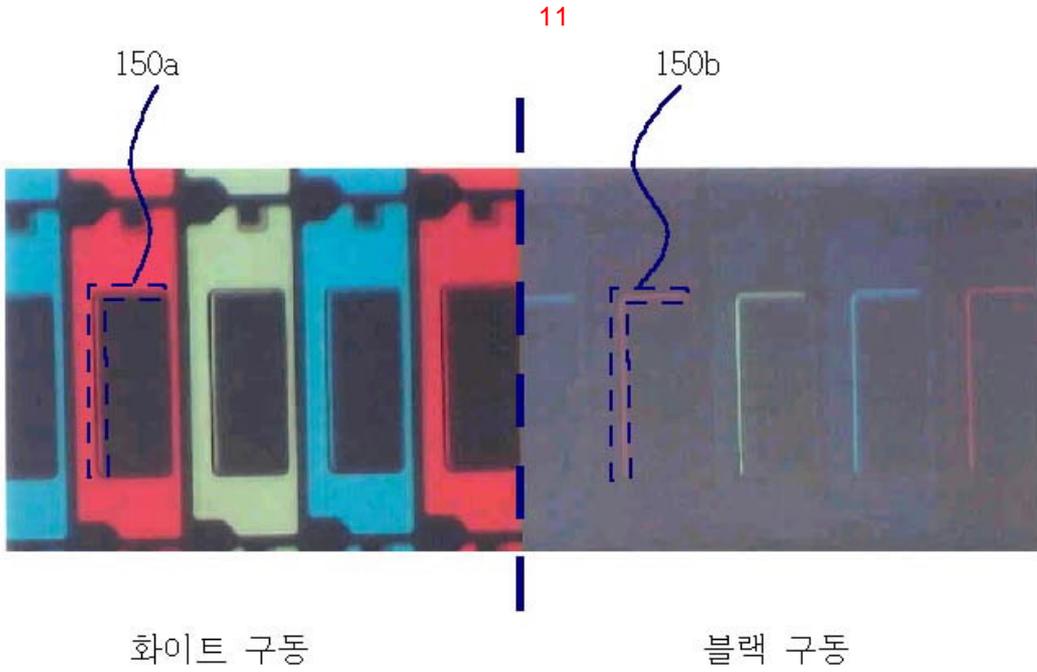
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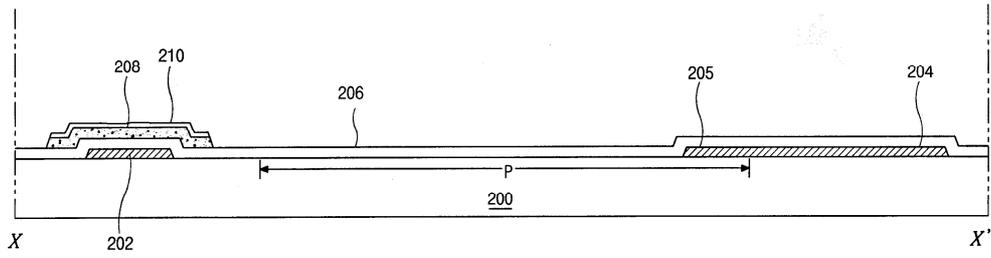




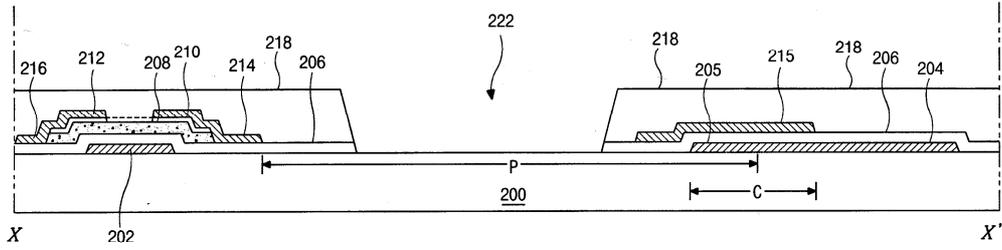




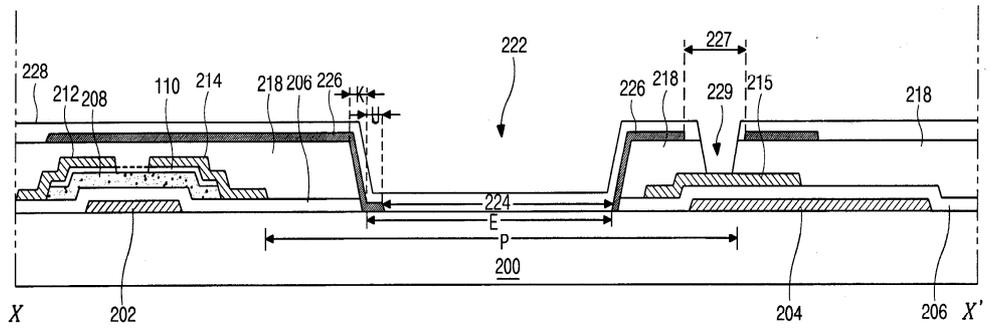
13a



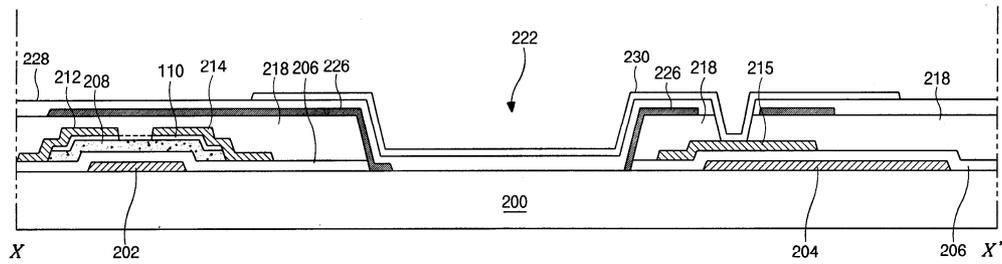
13b



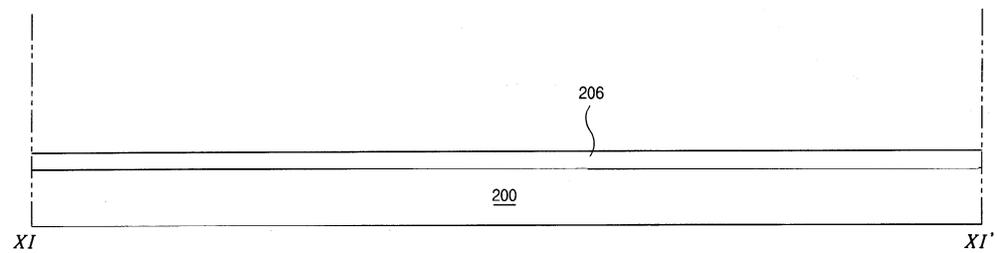
13c



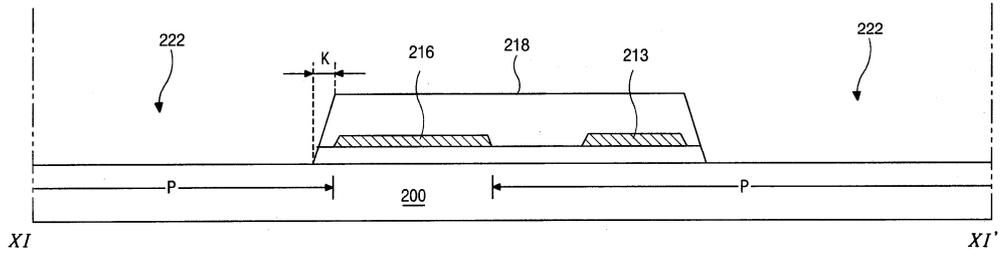
13d



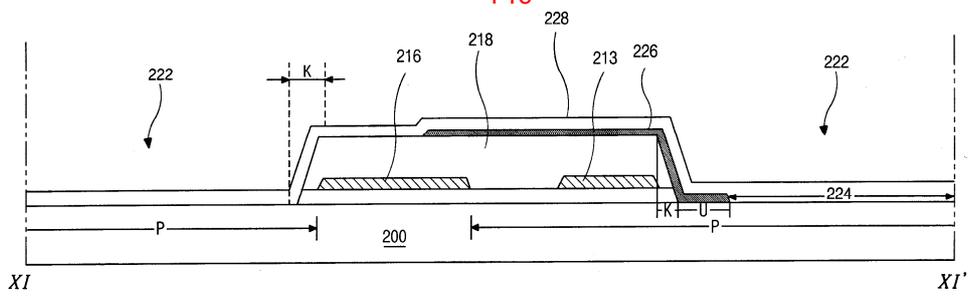
14a



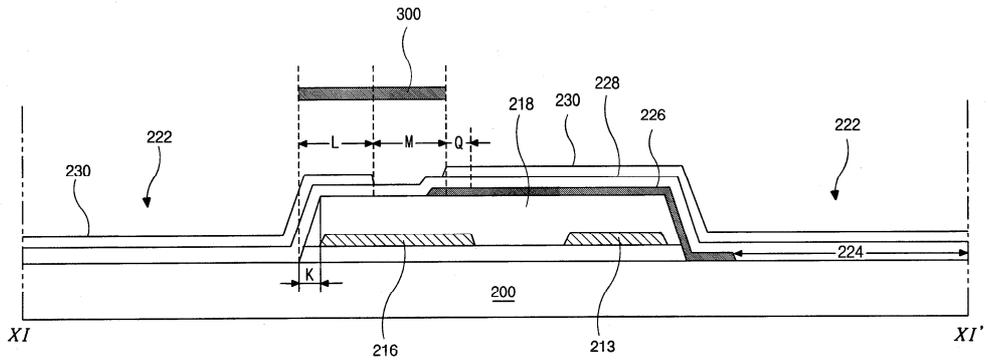
14b



14c



14d



专利名称(译)	用于反射透射型液晶显示装置的阵列基板及其制造方法		
公开(公告)号	KR1020030071114A	公开(公告)日	2003-09-03
申请号	KR1020020010657	申请日	2002-02-27
[标]申请(专利权)人(译)	乐金显示有限公司		
申请(专利权)人(译)	LG显示器有限公司		
当前申请(专利权)人(译)	LG显示器有限公司		
[标]发明人	HA KYOUNGSU 하경수 BAEK HEUMIL 백흠일 KIM DONGGUK 김동국		
发明人	하경수 백흠일 김동국		
IPC分类号	G02F1/1362 G02F1/1335		
CPC分类号	G02F1/133512 G02F1/136227 G02F1/133555		
其他公开文献	KR100787815B1		
外部链接	Espacenet		

摘要(译)

液晶显示装置技术领域本发明涉及液晶显示装置，更具体地涉及其中反射部分和透射部分同时形成在单个像素区域中的半透半反液晶显示装置。根据本发明的用于半透半反型液晶显示器的阵列基板的结构的特征在于，包括透射孔的反射板形成在透明像素电极上以限定透射部分和反射部分以及透射部分，该透射部分是光-反射余量进一步设计为阻挡漏光区域。由于这种结构可以有效地阻挡遮光区域，因此可以制造具有高图像质量的反射-透射型液晶显示装置。 8

